

# Quantum Oscillations in a Nondegenerate 2D Electron System on He

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## Introduction

### Shubnikov de Haas effect in degenerate 2DEG

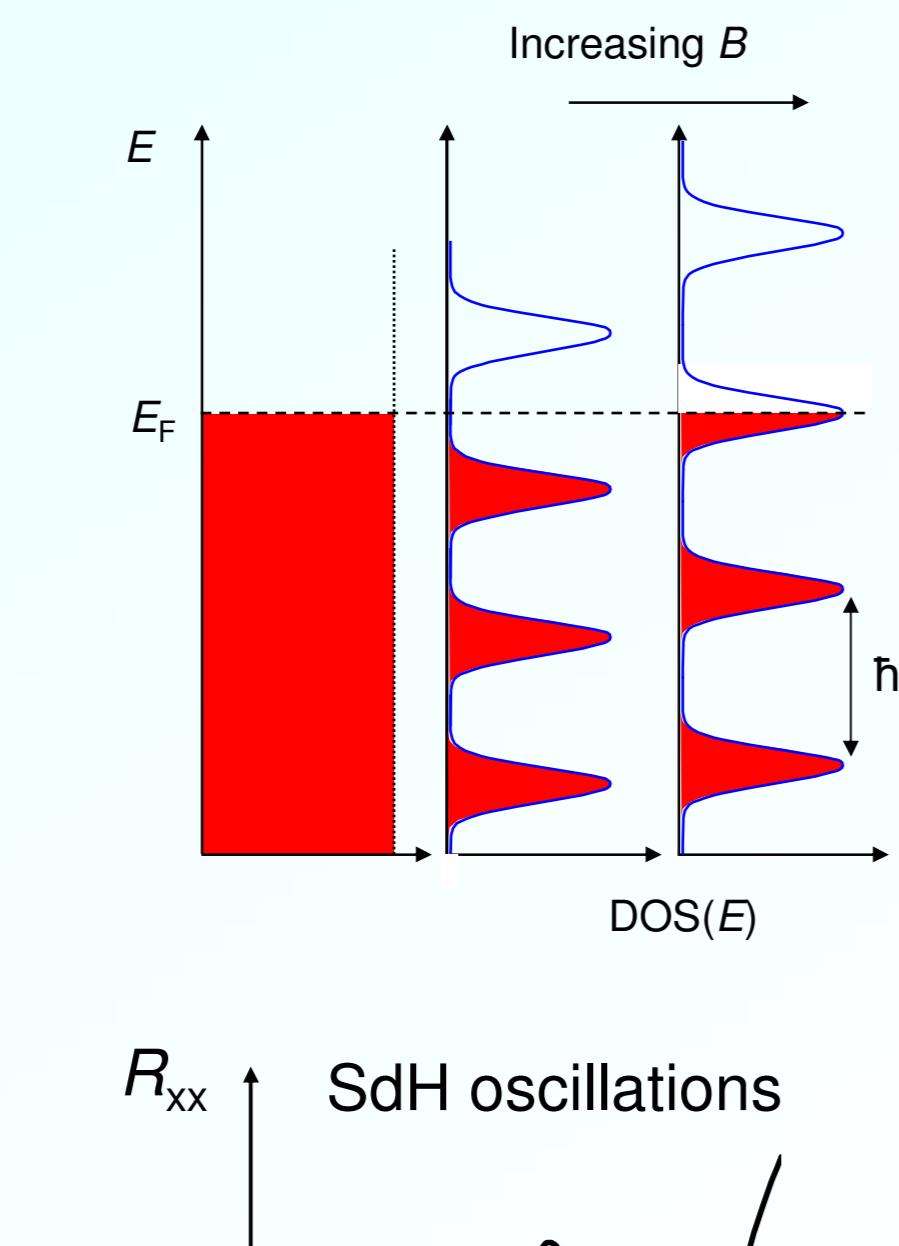
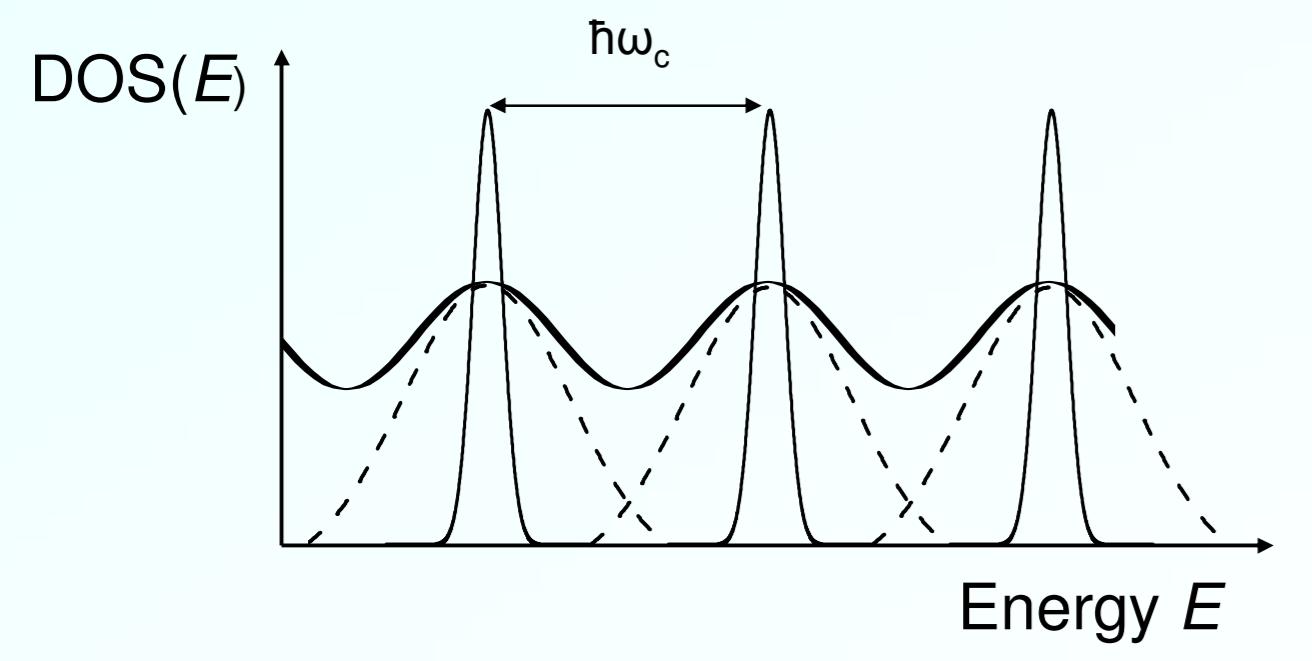
Quantum degenerate electron gas:

$$E_F = \frac{\pi \hbar^2 n_s}{m_e} \gg k_B T_e$$

In  $B$ -field perpendicular to 2D-plane:

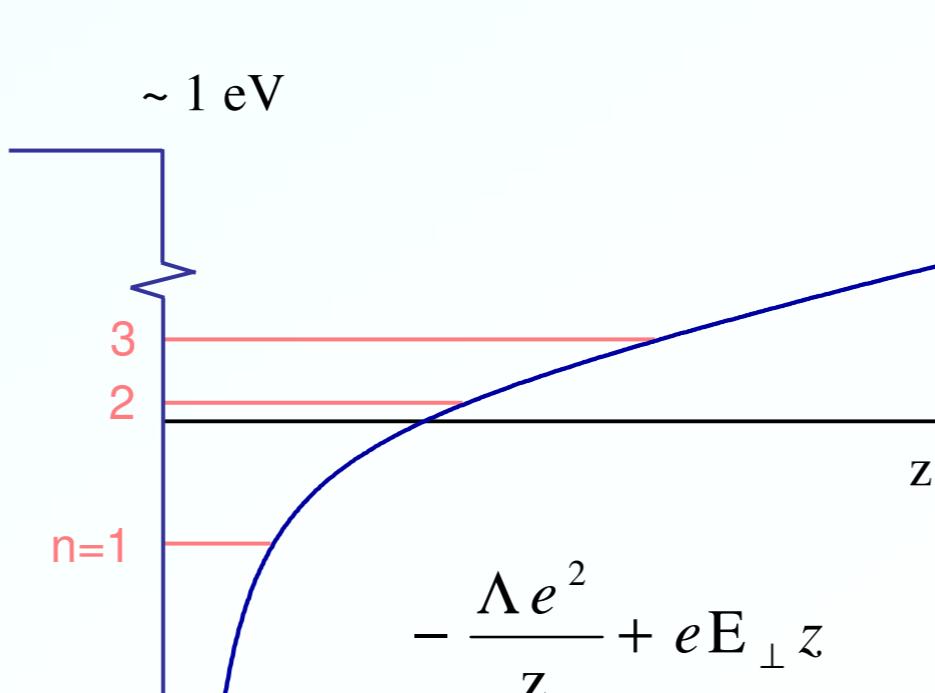
$$E = \hbar \omega_c (l + \frac{1}{2}), \quad l = 0, 1, 2, \dots$$

Modulated density of states (DOS)

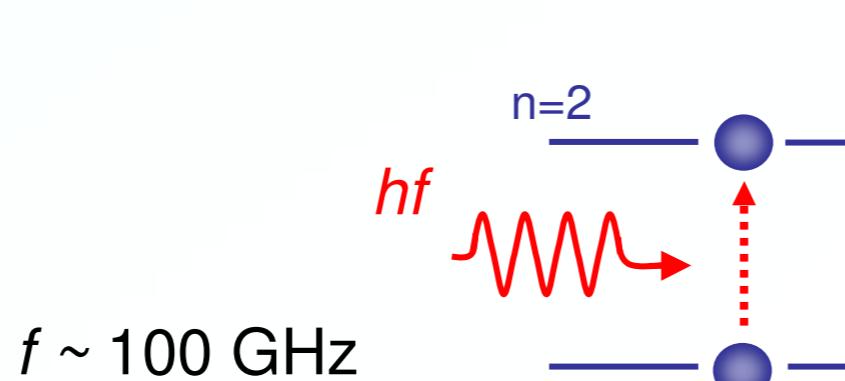


### Inter-subband oscillations in electrons on He

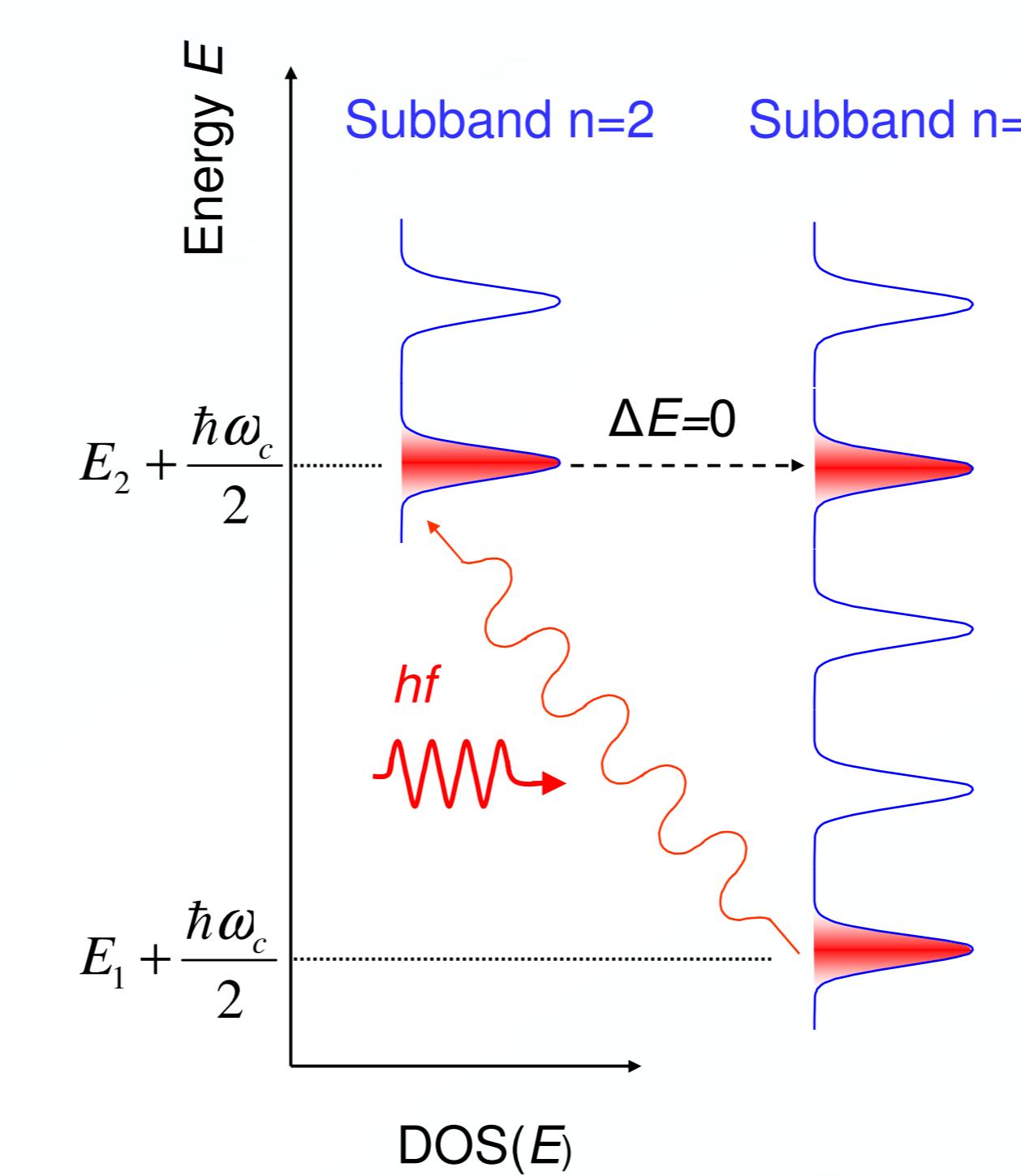
Surface states form subbands:



Inter-subband absorption:

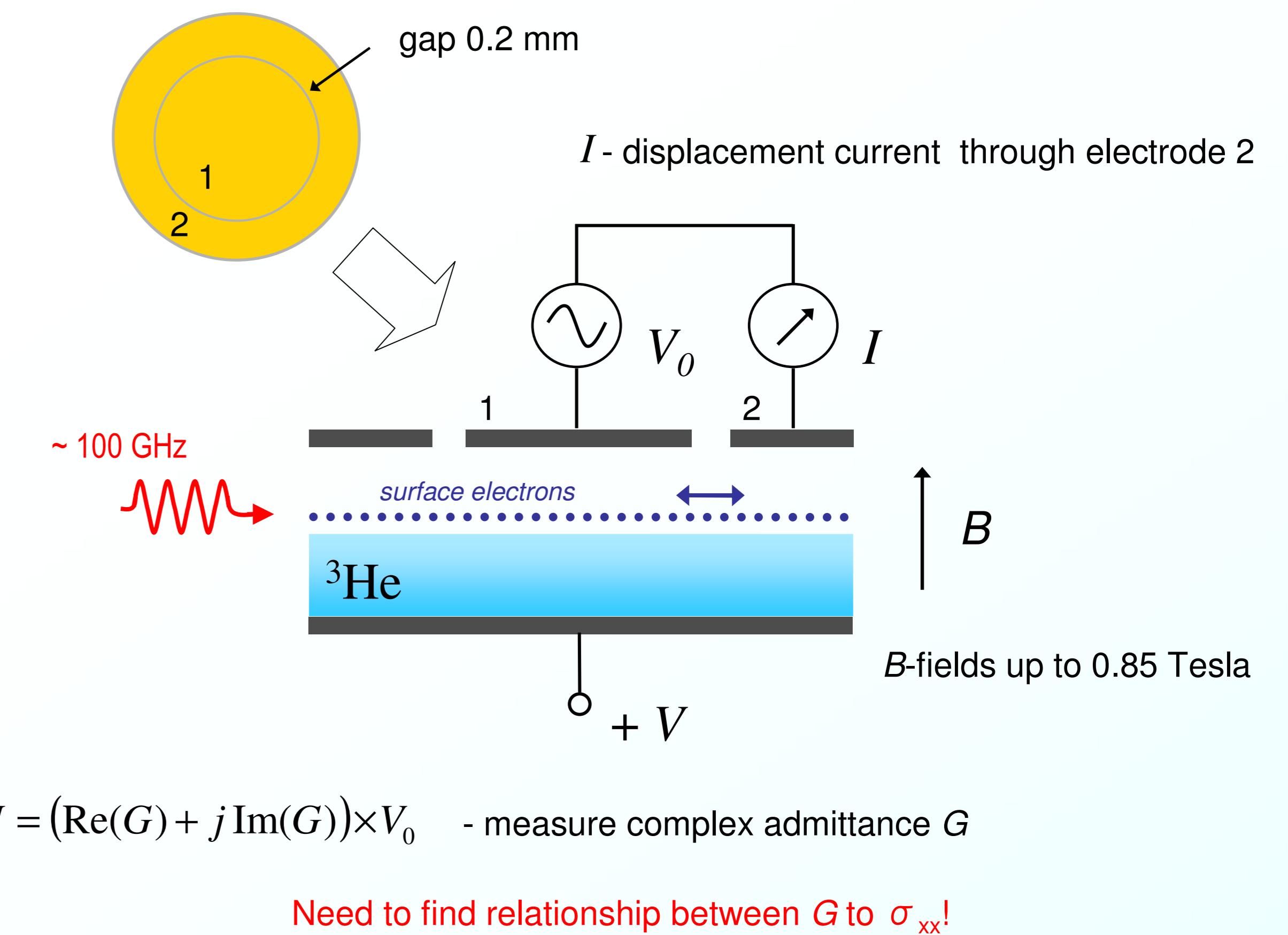


In  $B$ -field:  $E = E_n + \hbar \omega_c (l + \frac{1}{2})$



## Experimental

Au plated Corbino disk

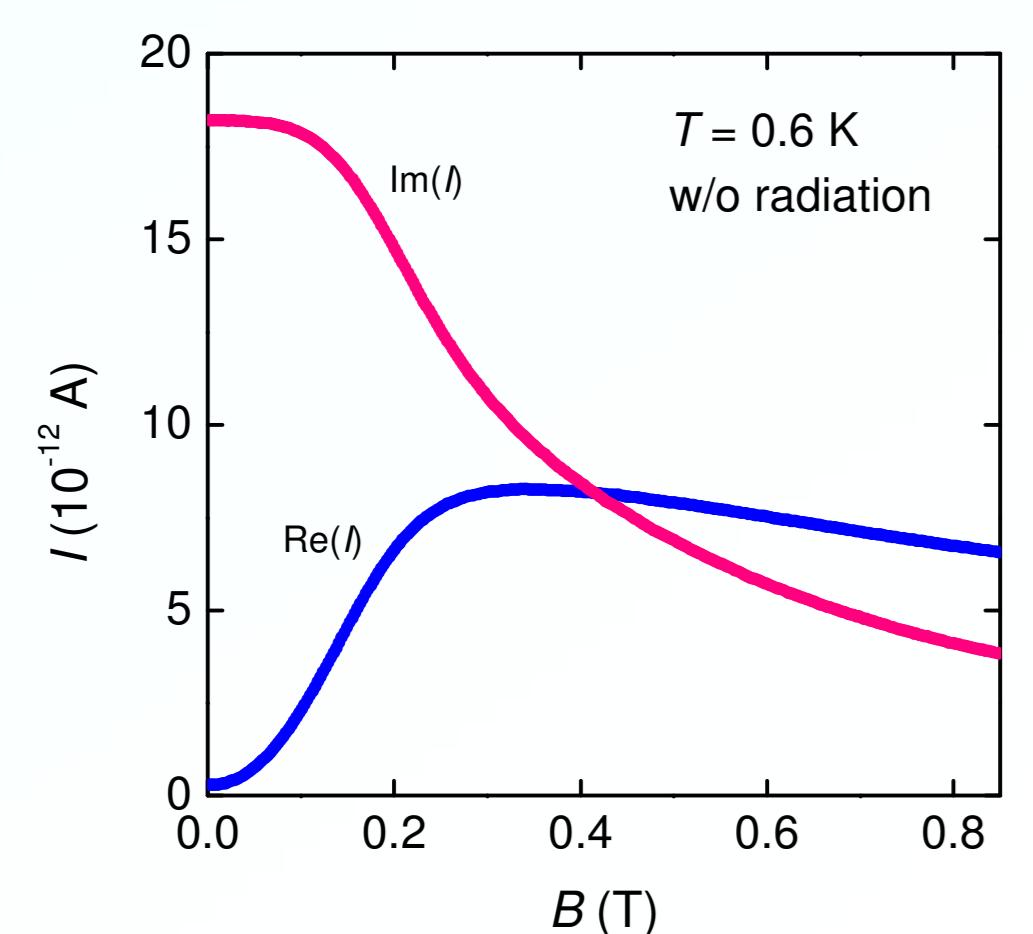


$$I = (\text{Re}(G) + j \text{Im}(G)) \times V_0 \quad - \text{measure complex admittance } G$$

Need to find relationship between  $G$  to  $\sigma_{xx}$ !

## Method

### Measured current



### Data analysis

Solve Maxwell equations to find field distribution:

$$G = I/V = \sum_{i=1}^{\infty} \frac{A_i}{\chi_1 - j \left( \frac{m \omega_p^2}{2 \pi f_i e^2 n_a} - \chi_2 \right)}$$

$$\text{where } \chi_1 + j \chi_2 = \sigma_{xx}^{-1}$$

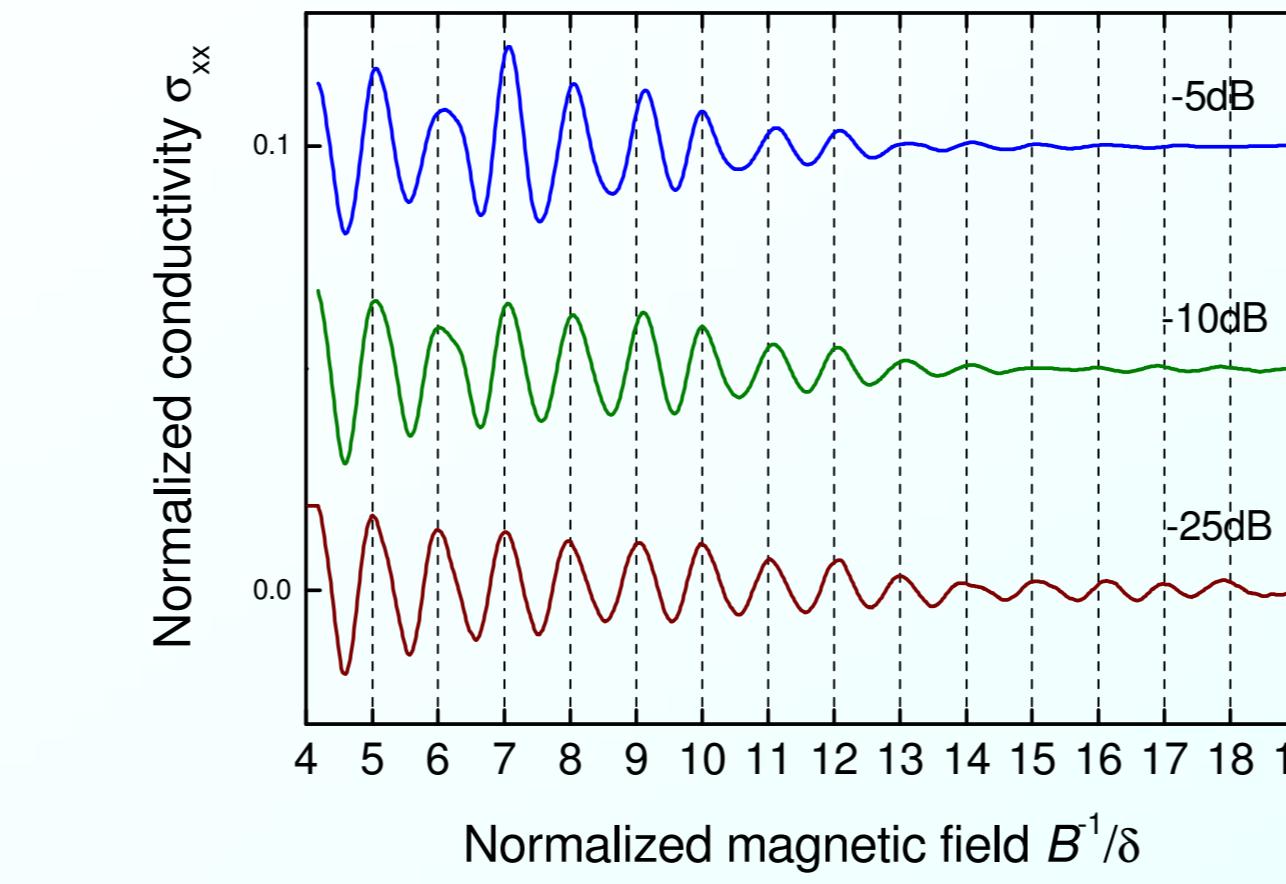
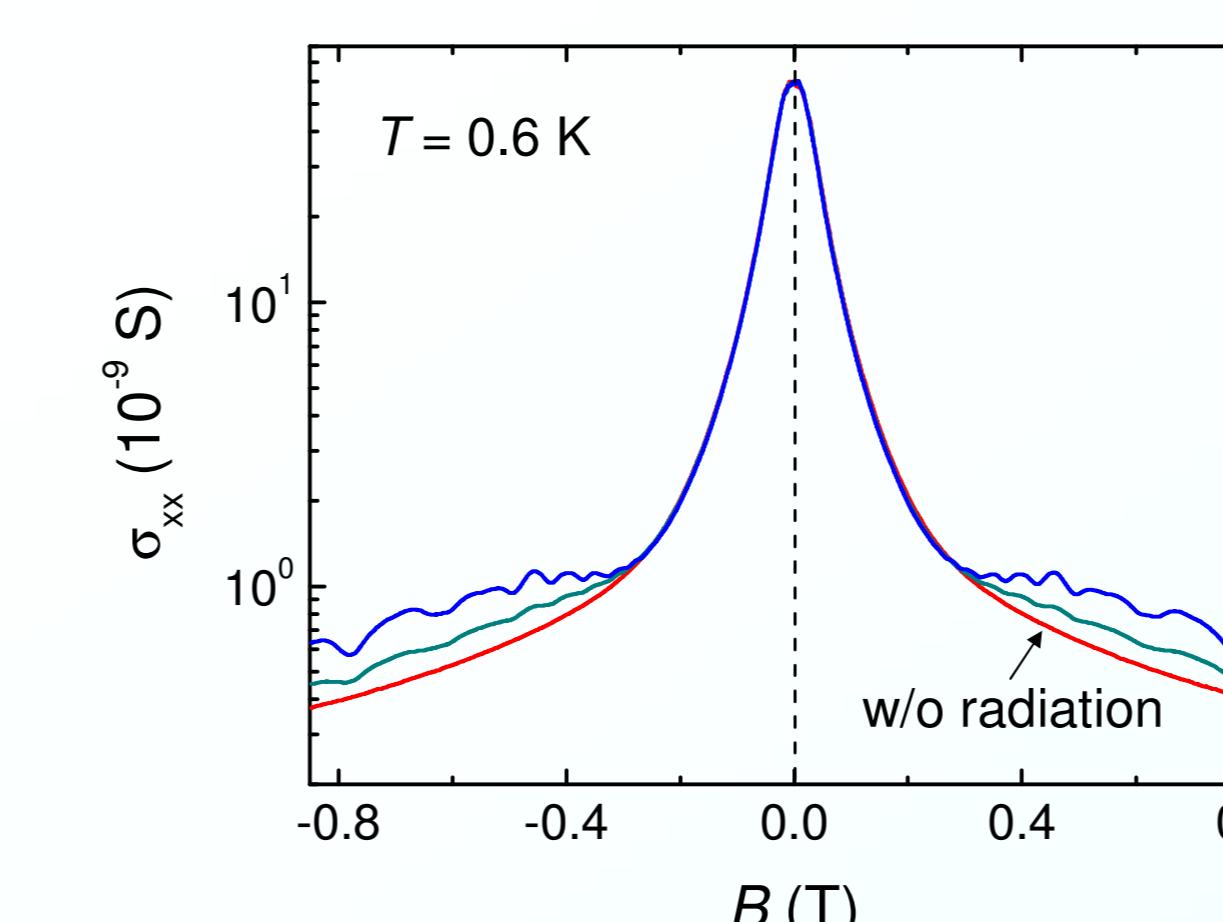
$$A_i = \frac{4\pi \sinh^2(\lambda_i d/R_e)}{\sinh^2(\lambda_i D/R_e)} \times$$

$$\times \frac{R_1 J_1(\lambda_i R_1/R_e) [R_2 J_1(\lambda_i R_2/R_e) - R_1 J_1(\lambda_i R_1/R_e)]}{R_e^2 J_0^2(\lambda_i)}$$

and

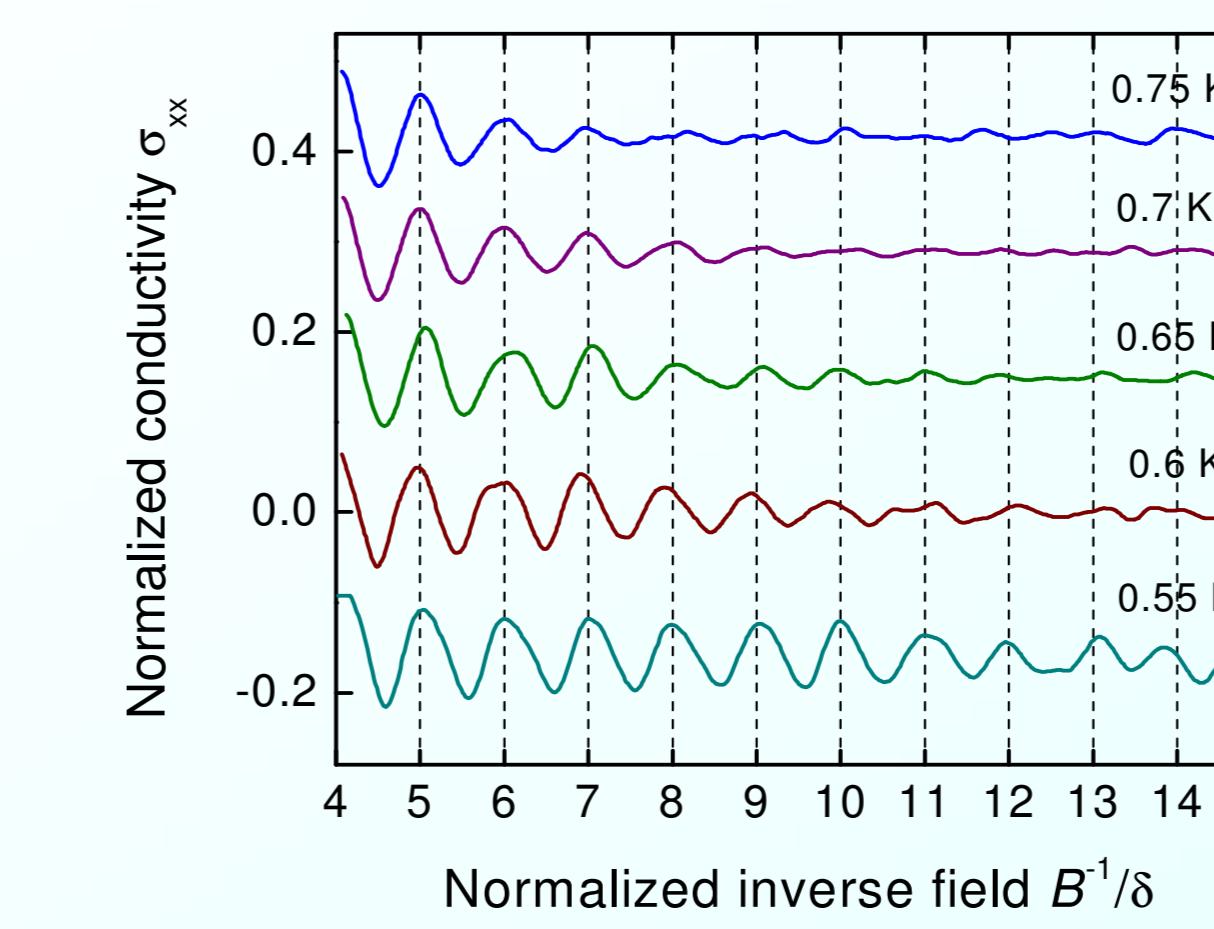
$$\omega_p = \frac{4\pi n_a \lambda_i}{m R_e [\coth(\lambda_i (D-d)/R_e) + \epsilon \coth(\lambda_i d/R_e)]}$$

### High-T oscillations

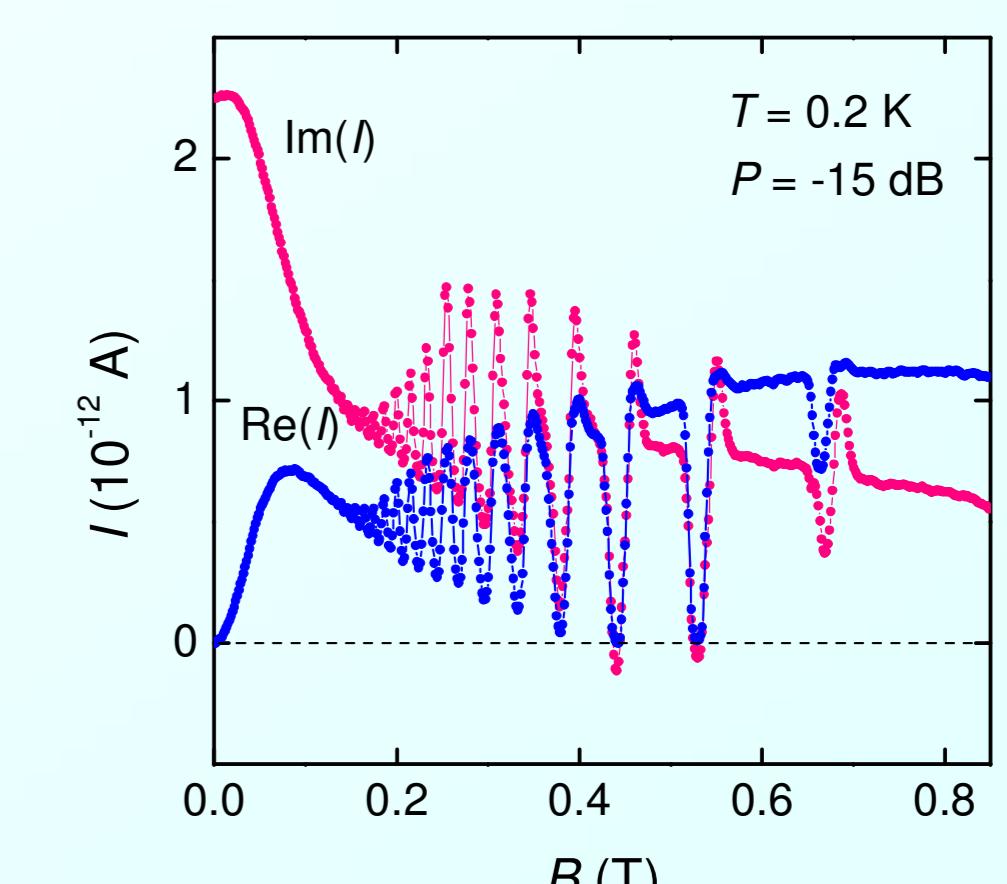


## Results

### T-dependence



### Current oscillations at T=0.2 K



## Summary

- Novel magneto-oscillations are demonstrated in nondegenerate quasi-2D electrons subjected to perpendicular magnetic fields
- The effect is governed by resonant inter-subband excitation and scattering mediated transitions between Landau levels of two subbands
- At  $T=0.2$  K system shows intriguing behavior which suggests the existence of zero-resistance states